

# **Dual High Voltage Trench MOS Barrier Schottky Rectifier**

Ultra Low  $V_F = 0.43 \text{ V}$  at  $I_F = 5 \text{ A}$ 



| PRIMARY CHARACTERISTICS                          |                |  |  |  |
|--------------------------------------------------|----------------|--|--|--|
| I <sub>F(AV)</sub>                               | 2 x 15 A       |  |  |  |
| V <sub>RRM</sub>                                 | 100 V          |  |  |  |
| I <sub>FSM</sub>                                 | 160 A          |  |  |  |
| V <sub>F</sub> at I <sub>F</sub> = 15 A (125 °C) | 0.62 V         |  |  |  |
| T <sub>J</sub> max.                              | 150 °C         |  |  |  |
| Package                                          | TO-220AB       |  |  |  |
| Circuit configuration                            | Common cathode |  |  |  |

#### **FEATURES**

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses

· High efficiency operation

ROHS
COMPLIANT
HALOGEN
FREE

- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106
- Material categorization: for definitions of compliance please see <a href="https://www.vishav.com/doc?99912"><u>www.vishav.com/doc?99912</u></a>

### **TYPICAL APPLICATIONS**

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters, and reverse battery protection.

### **MECHANICAL DATA**

Case: TO-220AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and

commercial grade

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

| <b>MAXIMUM RATINGS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)                       |            |                               |             |      |  |
|----------------------------------------------------------------------------------------------|------------|-------------------------------|-------------|------|--|
| PARAMETER                                                                                    |            | SYMBOL                        | V30100CI    | UNIT |  |
| Maximum repetitive peak reverse voltage                                                      |            | $V_{RRM}$                     | 100         | V    |  |
| Maximum DC reverse voltage                                                                   |            | $V_{DC}$                      | 80          | V    |  |
| Maximum average forward rectified current (fig. 1)                                           | per device |                               | 30          | А    |  |
|                                                                                              | per diode  | I <sub>F(AV)</sub>            | 15          |      |  |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode |            | I <sub>FSM</sub>              | 160         | А    |  |
| Operating junction temperature range                                                         |            | T <sub>J</sub> <sup>(1)</sup> | -40 to +150 | °C   |  |
| Storage temperature range                                                                    |            | T <sub>STG</sub>              | -55 to +150 |      |  |

#### Note

<sup>(1)</sup> The heat generated must be less than the thermal conductivity from junction to ambient: dP<sub>D</sub>/dT<sub>J</sub> <1/ R<sub>BJA</sub>



| <b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted) |                        |                         |                               |      |      |      |
|-----------------------------------------------------------------------------------|------------------------|-------------------------|-------------------------------|------|------|------|
| PARAMETER                                                                         | TEST CONDITIONS        |                         | SYMBOL                        | TYP. | MAX. | UNIT |
| Instantaneous forward voltage per diode                                           | I <sub>F</sub> = 5 A   | T <sub>A</sub> = 25 °C  | V <sub>F</sub> <sup>(1)</sup> | 0.50 | -    | . v  |
|                                                                                   | I <sub>F</sub> = 7.5 A |                         |                               | 0.55 | -    |      |
|                                                                                   | I <sub>F</sub> = 15 A  |                         |                               | 0.70 | 0.77 |      |
|                                                                                   | I <sub>F</sub> = 5 A   | T <sub>A</sub> = 125 °C |                               | 0.43 | -    |      |
|                                                                                   | I <sub>F</sub> = 7.5 A |                         |                               | 0.50 | -    |      |
|                                                                                   | I <sub>F</sub> = 15 A  |                         |                               | 0.62 | 0.68 |      |
| Reverse current per diode                                                         | V - 80 V               | T <sub>A</sub> = 25 °C  | I <sub>R</sub> <sup>(2)</sup> | 0.01 | -    | m A  |
|                                                                                   | V <sub>R</sub> = 80 V  | T <sub>A</sub> = 125 °C |                               | 7.0  | -    |      |
|                                                                                   | V <sub>R</sub> = 100 V | T <sub>A</sub> = 25 °C  |                               | -    | 0.5  | mA   |
|                                                                                   |                        | T <sub>A</sub> = 125 °C |                               | 12.0 | 30   |      |
| Junction capacitance                                                              | 4 V, 1MHz              |                         | CJ                            | 1450 | -    | pF   |

#### Notes

 $^{(1)}\,$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

(2) Pulse test: Pulse width  $\leq 5 \text{ ms}$ 

| THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted) |                 |          |      |  |  |
|-------------------------------------------------------------------------|-----------------|----------|------|--|--|
| PARAMETER                                                               | SYMBOL          | V30100CI | UNIT |  |  |
| Typical thermal resistance per device                                   | $R_{\theta JC}$ | 1.8      | °C/W |  |  |

| ORDERING INFORMATION (Example) |                 |              |               |               |  |  |
|--------------------------------|-----------------|--------------|---------------|---------------|--|--|
| PREFERRED P/N                  | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE |  |  |
| V30100CI-M3/P                  | 1.88            | Р            | 50/tube       | Tube          |  |  |



### **RATINGS AND CHARACTERISTICS CURVES** (T<sub>A</sub> = 25 °C unless otherwise noted)

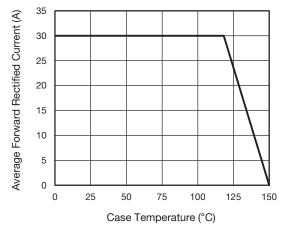


Fig. 1 - Forward Current Derating Curve

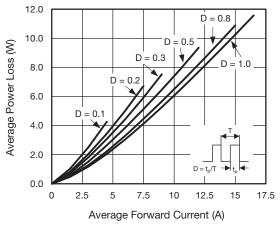


Fig. 2 - Forward Power Loss Characteristics Per Diode

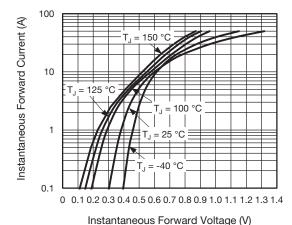


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

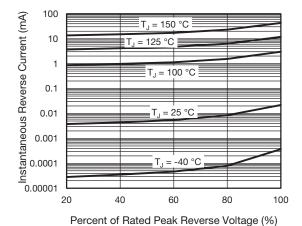


Fig. 4 - Typical Reverse Characteristics Per Diode

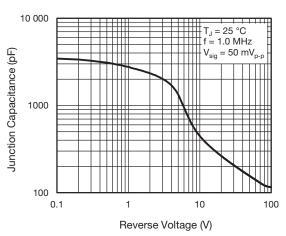


Fig. 5 - Typical Junction Capacitance

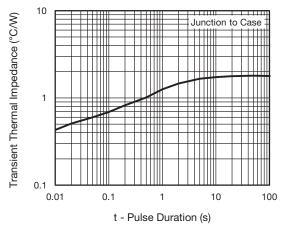
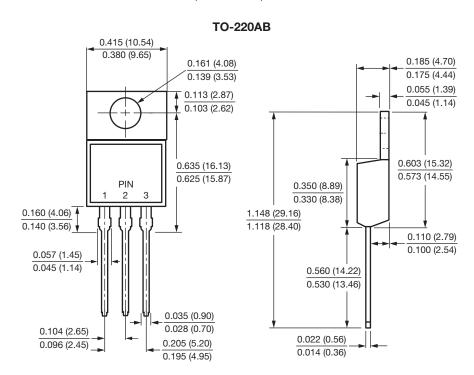


Fig. 6 - Typical Transient Thermal Impedance Per Device



### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)





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